

# 2.5V Drive Nch MOSFET

## RTF015N03

### ●Structure

Silicon N-channel MOSFET

### ●Features

- 1) Low On-resistance.
- 2) Space saving, small surface mount package (TUMT3).
- 3) Low voltage drive (2.5V drive).

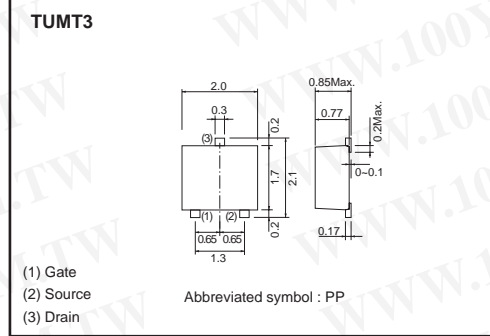
### ●Applications

Switching

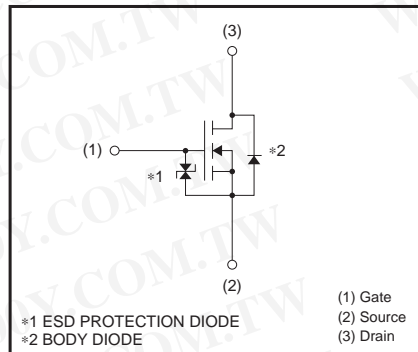
### ●Packaging specifications

Type	Package	Taping
	Code	TL
	Basic ordering unit (pieces)	3000
RTF015N03		○

### ●Dimensions (Unit : mm)



### ●Inner circuit



### ●Absolute maximum ratings (Ta=25°C)

Parameter	Symbol	Limits	Unit	
Drain-source voltage	$V_{DS}$	30	V	
Gate-source voltage	$V_{GS}$	12	V	
Drain current	Continuous	$I_D$	±1.5	A
	Pulsed	$I_{DP}$ *1	±6.0	A
Source current (Body diode)	Continuous	$I_S$	0.6	A
	Pulsed	$I_{SP}$ *1	6.0	A
Total power dissipation	$P_D$ *2	0.8	W	
Channel temperature	$T_{ch}$	150	°C	
Range of storage temperature	$T_{stg}$	-55 to +150	°C	

\*1  $P_w \leq 10\mu s$ , Duty cycle  $\leq 1\%$   
\*2 Mounted on a ceramic board

### ●Thermal resistance

Parameter	Symbol	Limits	Unit
Channel to ambient	$R_{th(ch-a)}$ *	156	°C/W

\* Mounted on a ceramic board

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## ●Electrical characteristics (Ta=25°C)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Gate-source leakage	I <sub>GSS</sub>	–	–	10	μA	V <sub>GS</sub> =12V, V <sub>DS</sub> =0V
Drain-source breakdown voltage	V <sub>(BR) DSS</sub>	30	–	–	V	I <sub>D</sub> =1mA, V <sub>GS</sub> =0V
Zero gate voltage drain current	I <sub>DSS</sub>	–	–	1	μA	V <sub>DS</sub> =30V, V <sub>GS</sub> =0V
Gate threshold voltage	V <sub>GS(th)</sub>	0.5	–	1.5	V	V <sub>DS</sub> =10V, I <sub>D</sub> =1mA
Static drain-source on-state resistance	R <sub>DS(on)*</sub>	–	170	240	mΩ	I <sub>D</sub> =1.5A, V <sub>GS</sub> =4.5V
		–	180	250	mΩ	I <sub>D</sub> =1.5A, V <sub>GS</sub> =4V
		–	240	340	mΩ	I <sub>D</sub> =1.5A, V <sub>GS</sub> =2.5V
Forward transfer admittance	Y <sub>fs</sub>   *	1.5	–	–	S	V <sub>DS</sub> =10V, I <sub>D</sub> =1.5A
Input capacitance	C <sub>iss</sub>	–	80	–	pF	V <sub>DS</sub> =10V
Output capacitance	C <sub>oss</sub>	–	14	–	pF	V <sub>GS</sub> =0V
Reverse transfer capacitance	C <sub>rss</sub>	–	12	–	pF	f=1MHz
Turn-on delay time	t <sub>d(on)</sub> *	–	7	–	ns	V <sub>DD</sub> =15V
Rise time	t <sub>r</sub> *	–	9	–	ns	I <sub>D</sub> =0.75A
Turn-off delay time	t <sub>d(off)</sub> *	–	15	–	ns	V <sub>GS</sub> =4.5V
Fall time	t <sub>f</sub> *	–	6	–	ns	R <sub>L</sub> =20Ω
Total gate charge	Q <sub>g</sub> *	–	1.6	2.2	nC	V <sub>DD</sub> =15V V <sub>GS</sub> =4.5V
Gate-source charge	Q <sub>gs</sub> *	–	0.5	–	nC	I <sub>D</sub> =1.5A
Gate-drain charge	Q <sub>gd</sub> *	–	0.3	–	nC	R <sub>L</sub> =10Ω R <sub>G</sub> =10Ω

\*Pulsed

## ●Body diode characteristics (Source-drain) (Ta=25°C)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Forward voltage	V <sub>SD</sub>	–	–	1.2	V	I <sub>S</sub> =0.6A, V <sub>GS</sub> =0V

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●Electrical characteristics curves

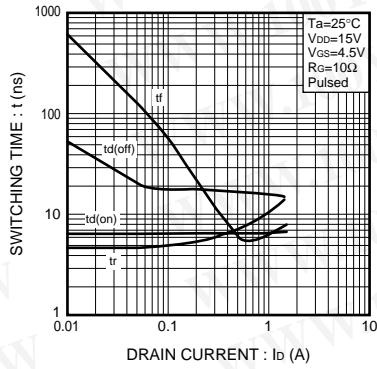


Fig.1 Switching Characteristics

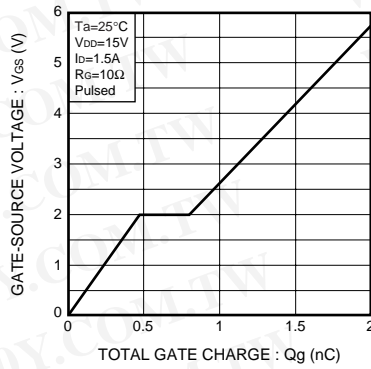


Fig.2 Dynamic Input Characteristics

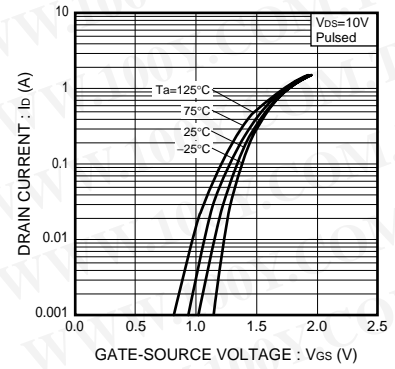


Fig.3 Typical Transfer Characteristics

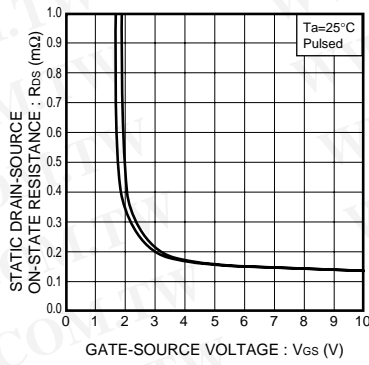


Fig.4 Static Drain-Source On-State Resistance vs. Gate source Voltage

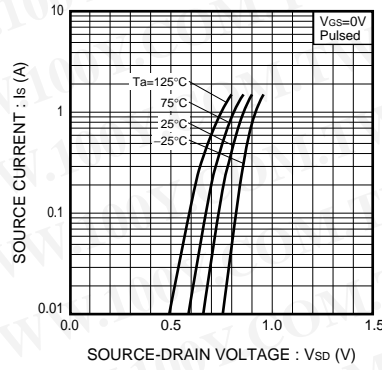


Fig.5 Source Current vs. Source-Drain Voltage

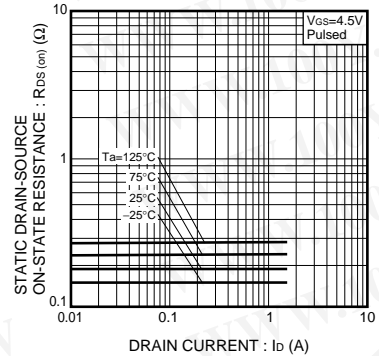


Fig.6 Static Drain-Source On-State Resistance vs. Drain Current ( I )

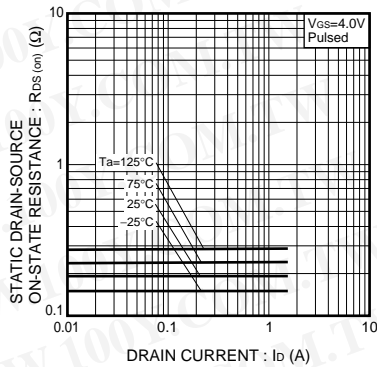


Fig.7 Static Drain-Source On-State Resistance vs. Drain Current ( II )

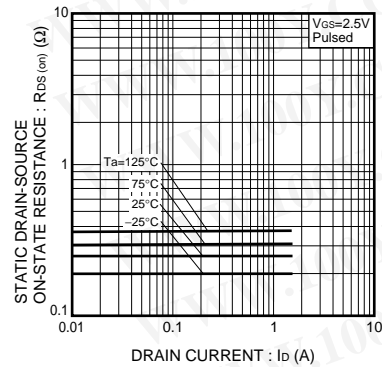


Fig.8 Static Drain-Source On-State Resistance vs. Drain Current ( III )

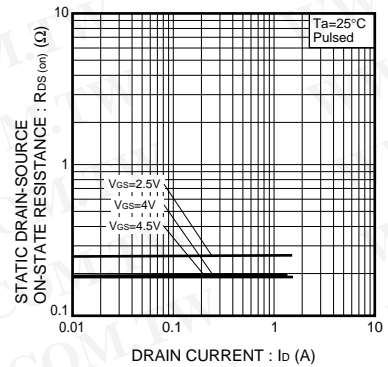


Fig.9 Static Drain-Source On-State Resistance vs. Drain Current ( IV )

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## Appendix

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